

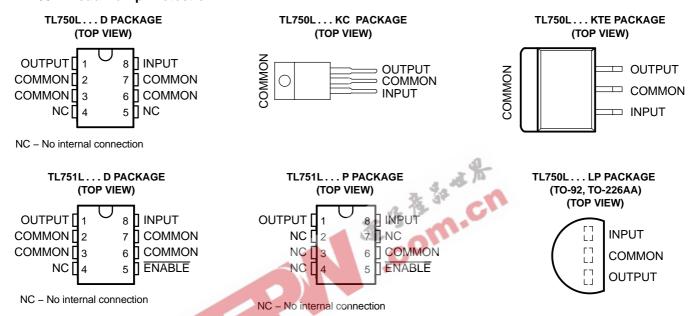
TL750L, TL751L SERIES LOW-DROPOUT VOLTAGE REGULATORS

SLVS017S-SEPTEMBER 1987-REVISED AUGUST 2005

FEATURES

- Very Low Dropout Voltage, Less Than 0.6 V at 150 mA
- Very Low Quiescent Current
- TTL- and CMOS-Compatible Enable on TL751L Series
- 60-V Load-Dump Protection

- Reverse Transient Protection Down to -50 V
- Internal Thermal-Overload Protection
- Overvoltage Protection
- Internal Overcurrent-Limiting Circuitry
- Less Than 500-μA Disable (TL751L Series)



DESCRIPTION/ORDERING INFORMATION

The TL750L and TL751L series of fixed-output voltage regulators offer 5-V, 8-V, 10-V, and 12-V options. The TL751L series also has an enable (ENABLE) input. When ENABLE is high, the regulator output is placed in the high-impedance state. This gives the designer complete control over power up, power down, or emergency shutdown.

The TL750L and TL751L series are low-dropout positive-voltage regulators specifically designed for battery-powered systems. These devices incorporate overvoltage and current-limiting protection circuitry, along with internal reverse-battery protection circuitry to protect the devices and the regulated system. The series is fully protected against 60-V load-dump and reverse-battery conditions. Extremely low quiescent current during full-load conditions makes these devices ideal for standby power systems.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

TL750L, TL751L SERIES LOW-DROPOUT VOLTAGE REGULATORS





ORDERING INFORMATION

TJ	V _O TYP AT 25°C	PACKAGE ⁽¹)	ORDERABLE PART NUMBER (2)	TOP-SIDE MARKING
		PowerFLEX™ – KTE	Reel of 2000	TL750L05CKTER	TL750L05C
			Tube of 75	TL750L05CD	50L05C
		SOIC – D	Reel of 2500	TL750L05CDR	30L03C
	5 V	30IC - D	Tube of 75	TL751L05CD	- 51L05C
	5 V		Reel of 2500	TL751L05CDR	51L05C
		TO-226/TO-92 – LP	Bulk of 1000	TL750L05CLP	750L05C
			Reel of 2000	TL750L05CLPR	750L05C
		TO-220 – KC	Tube of 50	TL750L05CKC	TL750L05C
		SOIC – D	Tube of 75	TL750L08CD	50L08C
	8 V	301C - D	Reel of 2500	TL750L08CDR	301000
		TO-226/TO-92 – LP	Bulk of 1000	TL750L08CLP	750L08C
0°C to 125°C		PDIP – P	Tube of 50	TL751L10CP	TL751L10C
		SOIC - D	Tube of 75	TL750L10CD	50L10C
			Reel of 2500	TL750L10CDR	302100
	10 V	3010 - D	Tube of 75	TL751L10CD	51L10C
			Reel of 2500	TL751L10CDR	312100
		TO-226/TO-92 – LP	Bulk of 1000	TL750L10CLP	750L10C
		10-220/10-92 – LF	Reel of 2000	TL750L10CLPR	7302100
			Tube of 75	TL750L12CD	50L12C
		SOIC - D	Reel of 2500	TL750L12CDR	30L12C
	12 V	3010 - 0	Tube of 75	TL751L12CD	51L12C
			Reel of 2500	TL751L12CDR	31L120
		TO-226/TO-92 – LP	Bulk of 1000	TL750L12CLP	750L12C

 ⁽¹⁾ Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.
 (2) For the most current ordering information, see the Package Option Addendum at the end of this data sheet.

DEVICE COMPONENT COUNT							
Transistors 20							
JFETs	2						
Diodes	5						
Resistors	16						





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Absolute Maximum Ratings⁽¹⁾

over operating junction temperature range (unless otherwise noted)

			MIN	MAX	UNIT
	Continuous input voltage			26	V
	Transient input voltage (2)	T _A = 25°C		60	V
	Continuous reverse input voltage			-15	V
	Transient reverse input voltage	t ≤ 100 ms		-50	V
T_J	Operating virtual junction temperature			150	°C
	Lead temperature	1,6 mm (1/16 in) for 10 s		260	°C
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The transient input voltage rating applies to the waveform shown in Figure 1.

Package Thermal Data⁽¹⁾

PACKAGE	BOARD	θЈС	θ_{JA}
PDIP (P)	High K, JESD 51-7	57°C/W	85°C/W
PowerFLEX [™] (KTE)	High K, JESD 51-5	3°C/W	23°C/W
SOIC (D)	High K, JESD 51-7	39°C/W	97°C/W
TO-226/TO-92 (LP)	High K, JESD 51-7	55°C/W	140°C/W
TO-220 (KC)	High K, JESD 51-5	3°C/W	19°C/W

⁽¹⁾ Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.

Recommended Operating Conditions

over recommended operating junction temperature range (unless otherwise noted)

				MIN	MAX	UNIT
			TL75xL05	6	26	
V	Input voltage	TL75xL08	9	26	V	
V _I	input voltage		TL75xL10	11	26	V
		TL75xL12	13	26		
V_{IH}	High-level ENABLE input voltage		TL75xLxx	2	15	V
V _{IL} (1)	Low-level ENABLE input voltage	$T_J = 25^{\circ}C$	TL75xLxx	-0.3	0.8	V
VIL	Low-level ENABLE Input voltage	$T_J = 0$ °C to 125°C	TL75xLxx	-0.15	0.8	V
Io	Output current		TL75xLxx	0	150	mA
T_J	Operating virtual junction temperature		TL75xLxxC	0	125	°C

The algebraic convention, in which the least positive (most negative) value is designated minimum, is used in this data sheet for ENABLE voltage levels and temperature only.

TL750L, TL751L SERIES LOW-DROPOUT VOLTAGE REGULATORS





TL75xL05 Electrical Characteristics⁽¹⁾

 $V_I = 14 \text{ V}, I_O = 10 \text{ mA}, T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITI	TI TI	UNIT			
			MIN	TYP	MAX	
Output voltage	V = 6 V to 26 V I = 0 to 150 mA	T _J = 25°C	4.8	5	5.2	V
Output voltage	$V_1 = 6 \text{ V to } 26 \text{ V}, I_0 = 0 \text{ to } 150 \text{ mA}$	$T_J = 0$ °C to 125°C	4.75		5.25	V
land the solletine college	V _I = 9 V to 16 V			5	10	\/
Input regulation voltage	V _I = 6 V to 26 V		6	30	mV	
Ripple rejection	V _I = 8 V to 18 V, f = 120 Hz		60	65		dB
Output regulation voltage	I _O = 5 mA to 150 mA			20	50	mV
Drawaytyseltana	I _O = 10 mA				0.2	V
Dropout voltage	I _O = 150 mA				0.6	V
Output noise voltage	f = 10 Hz to 100 kHz			500		μV
	I _O = 150 mA		10	12		
Input bias current	$V_{I} = 6 \text{ V to } 26 \text{ V}, I_{O} = 10 \text{ mA}, T_{J} = 0^{\circ} \text{ C}$	5°C 1			mA	
	ENABLE ≥ 2 V	8		0.5		

⁽¹⁾ Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1-μF capacitor across the input and a 10-μF capacitor, with equivalent series resistance of less than 0.4 Ω, across the output.

TL75xL08 Electrical Characteristics⁽¹⁾

 $V_I = 14 \text{ V}$, $I_O = 10 \text{ mA}$, $T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITI	TI TI	UNIT				
			MIN	TYP	MAX		
Output voltage	$V_1 = 9 \text{ V to } 26 \text{ V}, I_0 = 0 \text{ to } 150 \text{ mA}$	$T_J = 25^{\circ}C$	7.68	8	8.32	V	
Output voltage	V ₁ = 9 V to 20 V, t ₀ = 0 to 130 mA	$T_J = 0$ °C to 125°C	7.6		8.4	V	
Input regulation valtage	$V_1 = 10 \ V \text{ to } 17 \ V$			10	20	m)/	
Input regulation voltage	$V_1 = 9 V \text{ to } 26 V$		25	50	mV		
Ripple rejection	V _I = 11 V to 21 V, f = 120 Hz		60	65		dB	
Output regulation voltage	I _O = 5 mA to 150 mA			40	80	mV	
Dropout voltage	I _O = 10 mA			0.2	V		
Dropout voltage	I _O = 150 mA			0.6	V		
Output noise voltage	f = 10 Hz to 100 kHz			500		μV	
	I _O = 150 mA		10	12			
Input bias current	$V_I = 9 \text{ V to } 26 \text{ V}, I_O = 10 \text{ mA}, T_J = 0^{\circ} \text{ C}$		1	2	mA		
	ENABLE ≥ 2 V			0.5			

⁽¹⁾ Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1-μF capacitor across the input and a 10-μF capacitor, with equivalent series resistance of less than 0.4 Ω, across the output.



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TL75xL10 Electrical Characteristics (1)

 $V_I = 14 \text{ V}, I_O = 10 \text{ mA}, T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITION	TI TI	UNIT				
			MIN	TYP	MAX		
Output voltage	V = 11 V to 26 V L = 0 to 150 mA	T _J = 25°C	9.6	10	10.4	V	
Output voltage	$V_I = 11 \text{ V to } 26 \text{ V}, I_O = 0 \text{ to } 150 \text{ mA}$	$T_J = 0$ °C to 125°C	9.5		10.5	V	
land to a sulation walter	V _I = 12 V to 19 V			10	25	mV	
Input regulation voltage	V _I = 11 V to 26 V	V _I = 11 V to 26 V					
Ripple rejection	V _I = 12 V to 22 V, f = 120 Hz	V _I = 12 V to 22 V, f = 120 Hz				dB	
Output regulation voltage	I _O = 5 mA to 150 mA	I _O = 5 mA to 150 mA				mV	
Description	I _O = 10 mA				0.2	V	
Dropout voltage	I _O = 150 mA	I _O = 150 mA					
Output noise voltage	f = 10 Hz to 100 kHz			700		μV	
	I _O = 150 mA		10	12			
Input bias current	V_I = 11 V to 26 V, I_O = 10 mA, T_J = 0°		1	2	mA		
	ENABLE ≥ 2 V	3_		0.5			

⁽¹⁾ Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1-μF capacitor across the input and a 10-μF capacitor, with equivalent series resistance of less than 0.4 Ω, across the output.

TL75xL12 Electrical Characteristics⁽¹⁾

 $V_1 = 14 \text{ V}$, $I_0 = 10 \text{ mA}$, $T_1 = 25^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITION	TI TI	UNIT			
			MIN	TYP	MAX	
Output voltage	V = 13 V to 26 V L = 0 to 150 mA	T _J = 25°C	11.52	12	12.48	V
Output voltage	$V_1 = 13 \text{ V to } 26 \text{ V}, I_0 = 0 \text{ to } 150 \text{ mA}$	$T_J = 0$ °C to 125°C	11.4		12.6	V
land an adation valence	V _I = 14 V to 19 V			15	30	mV
Input regulation voltage	V _I = 13 V to 26 V	$V_{I} = 13 \text{ V to } 26 \text{ V}$				
Ripple rejection	V _I = 13 V to 23 V, f = 120 Hz		50	55		dB
Output regulation voltage	I _O = 5 mA to 150 mA			50	120	mV
Drangust valtage	I _O = 10 mA			0.2	V	
Dropout voltage	I _O = 150 mA	I _O = 150 mA				
Output noise voltage	f = 10 Hz to 100 kHz	f = 10 Hz to 100 kHz				μV
	I _O = 150 mA		10	12	mA	
Input bias current	$V_{I} = 13 \text{ V to } 26 \text{ V}, I_{O} = 10 \text{ mA}, T_{J} = 0^{\circ}$		1	2		
	ENABLE ≥ 2 V			0.5		

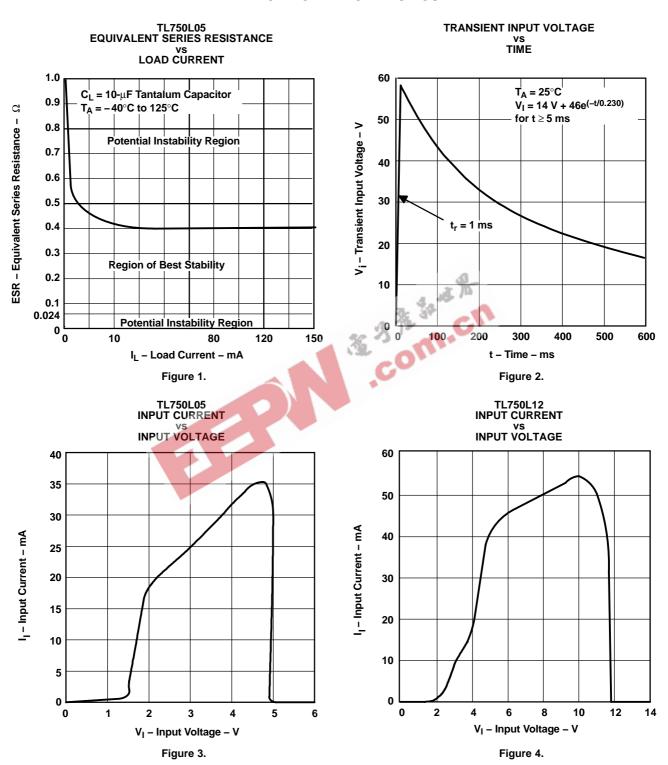
⁽¹⁾ Pulse-testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately. All characteristics are measured with a 0.1-μF capacitor across the input and a 10-μF capacitor, with equivalent series resistance of less than 0.4 Ω, across the output.

PARAMETER MEASUREMENT INFORMATION

The TL750L, TL751L series are low-dropout regulators. This means that capacitance loading is important to the performance of the regulator because it is a vital part of the control loop. The capacitor value and its equivalent series resistance (ESR) both affect the control loop and must be defined for the load range and temperature range. Figure 1 shows the recommended range of ESR for a given load with a 10-μF capacitor on the output.



TYPICAL CHARACTERISTICS







10-Feb-2007

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾ I	Lead/Ball Finisl	h MSL Peak Temp ⁽³⁾
5962-9166901Q2A	OBSOLETE	LCCC	FK	20		TBD	Call TI	Call TI
5962-9166901QPA	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI
TL750L05CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL750L05CDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL750L05CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL750L05CDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL750L05CKC	NRND	TO-220	KC	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type
TL750L05CKCE3	NRND	TO-220	KC	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type
TL750L05CKCS	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type
TL750L05CKTER	NRND	PFM	KTE	3	2000	TBD	CU SNPB	Level-1-220C-UNLIM
TL750L05CLP	ACTIVE	TO-92	LP	3	1000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type
TL750L05CLPE3	ACTIVE	TO-92	LP	3	1000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type
TL750L05CLPM	OBSOLETE	TO-92	LP	3		TBD	Call TI	Call TI
TL750L05CLPR	ACTIVE	TO-92	LP	3	2000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type
TL750L05CLPRE3	ACTIVE	TO-92	LP	3	2000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type
TL750L05CP	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI
TL750L05QD	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
TL750L05QDR	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
TL750L05QKC	OBSOLETE	TO-220	KC	3		TBD	Call TI	Call TI
TL750L05QLP	OBSOLETE	TO-92	LP	3		TBD	Call TI	Call TI
TL750L05QP	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI
TL750L08CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
TL750L08CDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
TL750L08CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
TL750L08CDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1YEAR
TL750L08CKC	OBSOLETE	TO-220	KC	3		TBD	Call TI	Call TI
TL750L08CLP	ACTIVE	TO-92	LP	3	1000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type
TL750L08CLPE3	ACTIVE	TO-92	LP	3	1000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type
TL750L08CP	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI
TL750L08QD	OBSOLETE	SOIC	D	8	-	TBD	Call TI	Call TI



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Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TL750L08QDR	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
TL750L08QKC	OBSOLETE	TO-220	KC	3		TBD	Call TI	Call TI
TL750L08QLP	OBSOLETE	TO-92	LP	3		TBD	Call TI	Call TI
TL750L10CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL750L10CDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL750L10CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL750L10CDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL750L10CKC	OBSOLETE	TO-220	KC	3		TBD	Call TI	Call TI
TL750L10CLP	ACTIVE	TO-92	LP	3	1000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type
TL750L10CLPE3	ACTIVE	TO-92	LP	3	1000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type
TL750L10CLPR	ACTIVE	TO-92	LP	3	2000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type
TL750L10CLPRE3	ACTIVE	TO-92	LP	3	2000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type
TL750L10CP	OBSOLETE	PDIP	P	8	~0	TBD	Call TI	Call TI
TL750L10QD	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
TL750L10QDR	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
TL750L10QKC	OBSOLETE	TO-220	KC	3		TBD	Call TI	Call TI
TL750L10QLP	OBSOLETE	TO-92	LP	3		TBD	Call TI	Call TI
TL750L10QP	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI
TL750L12CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL750L12CDE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL750L12CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL750L12CDRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL750L12CKC	OBSOLETE	TO-220	KC	3		TBD	Call TI	Call TI
TL750L12CLP	ACTIVE	TO-92	LP	3	1000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type
TL750L12CLPE3	ACTIVE	TO-92	LP	3	1000	Pb-Free (RoHS)	CU SN	N / A for Pkg Type
TL750L12CP	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI
TL750L12QD	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
TL750L12QDR	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
TL750L12QKC	OBSOLETE	TO-220	KC	3		TBD	Call TI	Call TI
TL750L12QLP	OBSOLETE	TO-92	LP	3		TBD	Call TI	Call TI
TL750L12QP	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
TL751L05CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)		Level-1-260C-UNLIM
TL751L05CDE4	ACTIVE	SOIC	D	8	75	Green (RoHS &	CU NIPDAU	Level-1-260C-UNLIM



PACKAGE OPTION ADDENDUM

10-Feb-2007

TL751L05CDRE4	Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TL751L05CDRE4							no Sb/Br)		
TL751L05CP	TL751L05CDR	ACTIVE	SOIC	D	8	2500	,	CU NIPDAU	Level-1-260C-UNLIM
TL751L05MFKB	TL751L05CDRE4	ACTIVE	SOIC	D	8	2500	`	CU NIPDAU	Level-1-260C-UNLIM
TL751L05MJGB	TL751L05CP	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI
TL751L05QD	TL751L05MFKB	OBSOLETE	LCCC	FK	20		TBD	Call TI	Call TI
TL751L0SQDR	TL751L05MJGB	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI
TL751L0SQP	TL751L05QD	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
TL751L10CD	TL751L05QDR	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
TL751L10CDE4	TL751L05QP	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI
TL751L10CDR	TL751L10CD	ACTIVE	SOIC	D	8	75	`	CU NIPDAU	Level-1-260C-UNLIM
TL751L10CDRE4	TL751L10CDE4	ACTIVE	SOIC	D	8	75	,	CU NIPDAU	Level-1-260C-UNLIM
TL751L10CP	TL751L10CDR	ACTIVE	SOIC	D	8	2500		CU NIPDAU	Level-1-260C-UNLIM
TL751L10CPE4	TL751L10CDRE4	ACTIVE	SOIC	D		2500		CU NIPDAU	Level-1-260C-UNLIM
TL751L10QD	TL751L10CP	ACTIVE	PDIP	Р	8	50	- W.	CU NIPDAU	N / A for Pkg Type
TL751L10QP OBSOLETE PDIP P 8 TBD Call TI Call TI TL751L12CD ACTIVE SOIC D 8 75 Green (RoHS & CU NIPDAU Level-1-260C-UN no Sb/Br) TL751L12CDE4 ACTIVE SOIC D 8 2500 Green (RoHS & CU NIPDAU Level-1-260C-UN no Sb/Br) TL751L12CDRE4 ACTIVE SOIC D 8 2500 Green (RoHS & CU NIPDAU Level-1-260C-UN no Sb/Br) TL751L12CP OBSOLETE PDIP P 8 TBD Call TI Call TI TL751L12MFKB OBSOLETE LCCC FK 20 TBD Call TI Call TI TL751L12QD OBSOLETE CDIP JG 8 TBD Call TI Call TI TL751L12QDR OBSOLETE SOIC D 8 TBD Call TI Call TI TL751L12QDR OBSOLETE SOIC D 8 TBD Call TI Call TI	TL751L10CPE4	ACTIVE	PDIP	Р	8	50		CU NIPDAU	N / A for Pkg Type
TL751L12CD ACTIVE SOIC D 8 75 Green (RoHS & CU NIPDAU Level-1-260C-UN no Sb/Br) TL751L12CDE4 ACTIVE SOIC D 8 75 Green (RoHS & CU NIPDAU Level-1-260C-UN no Sb/Br) TL751L12CDR ACTIVE SOIC D 8 2500 Green (RoHS & CU NIPDAU Level-1-260C-UN no Sb/Br) TL751L12CDRE4 ACTIVE SOIC D 8 2500 Green (RoHS & CU NIPDAU Level-1-260C-UN no Sb/Br) TL751L12CP OBSOLETE PDIP P 8 TBD Call TI Call TI TL751L12MFKB OBSOLETE LCCC FK 20 TBD Call TI Call TI TL751L12MJGB OBSOLETE CDIP JG 8 TBD Call TI Call TI TL751L12QDD OBSOLETE SOIC D 8 TBD Call TI Call TI TL751L12QDR OBSOLETE SOIC D 8 TBD Call TI Call TI	TL751L10QD	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
TL751L12CDE4	TL751L10QP	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI
TL751L12CDR	TL751L12CD	ACTIVE	SOIC	D	8	75	`	CU NIPDAU	Level-1-260C-UNLIM
TL751L12CDRE4	TL751L12CDE4	ACTIVE	SOIC	D	8	75	`	CU NIPDAU	Level-1-260C-UNLIM
TL751L12CP	TL751L12CDR	ACTIVE	SOIC	D	8	2500	`	CU NIPDAU	Level-1-260C-UNLIM
TL751L12MFKB OBSOLETE LCCC FK 20 TBD Call TI Call TI TL751L12MJGB OBSOLETE CDIP JG 8 TBD Call TI Call TI TL751L12QD OBSOLETE SOIC D 8 TBD Call TI Call TI TL751L12QDR OBSOLETE SOIC D 8 TBD Call TI Call TI	TL751L12CDRE4	ACTIVE	SOIC	D	8	2500	`	CU NIPDAU	Level-1-260C-UNLIM
TL751L12MJGB OBSOLETE CDIP JG 8 TBD Call TI Call TI TL751L12QD OBSOLETE SOIC D 8 TBD Call TI Call TI TL751L12QDR OBSOLETE SOIC D 8 TBD Call TI Call TI	TL751L12CP	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI
TL751L12QD OBSOLETE SOIC D 8 TBD Call TI Call TI TL751L12QDR OBSOLETE SOIC D 8 TBD Call TI Call TI	TL751L12MFKB	OBSOLETE	LCCC	FK	20		TBD	Call TI	Call TI
TL751L12QDR OBSOLETE SOIC D 8 TBD Call TI Call TI	TL751L12MJGB	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI
	TL751L12QD	OBSOLETE	SOIC	D	8	_	TBD	Call TI	Call TI
TI 751I 12OP OBSOLETE PDIP P 8 TRD Call TI Call TI	TL751L12QDR	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI
TETOTETE AND CONTROL TO THE CALL IT CALL IT	TL751L12QP	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI

(1) The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

10-Feb-2007

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

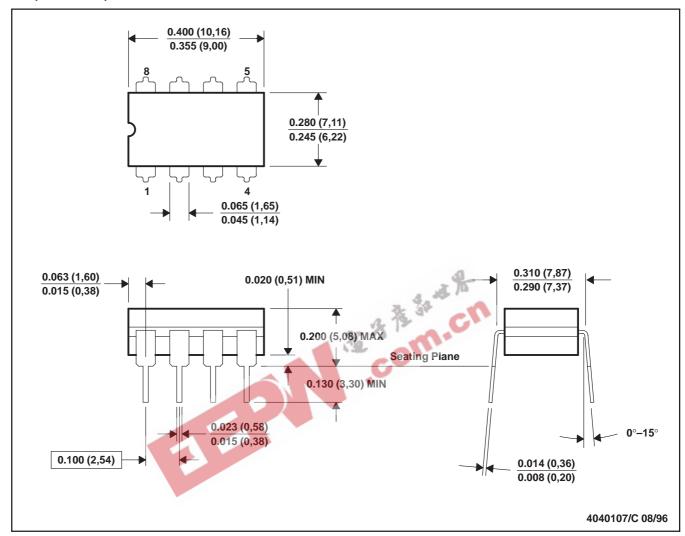
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JG (R-GDIP-T8)

CERAMIC DUAL-IN-LINE



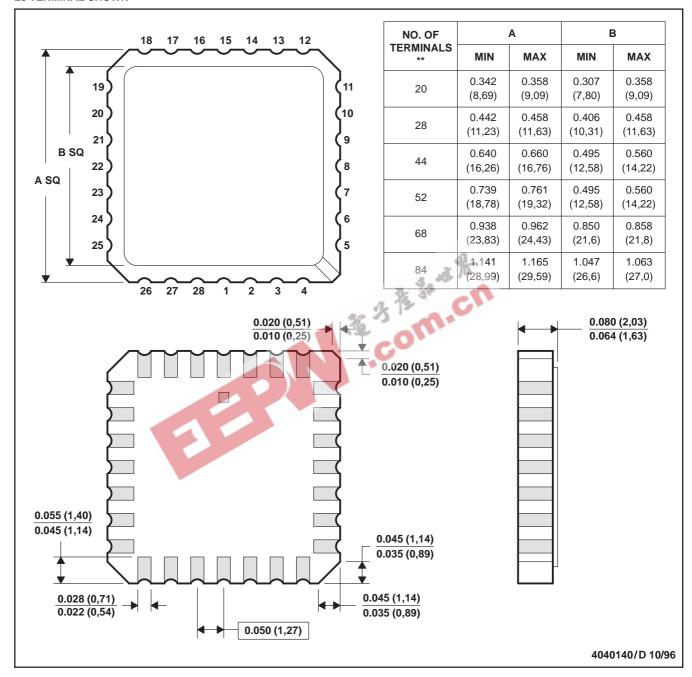
NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP1-T8

FK (S-CQCC-N**)

28 TERMINAL SHOWN

LEADLESS CERAMIC CHIP CARRIER

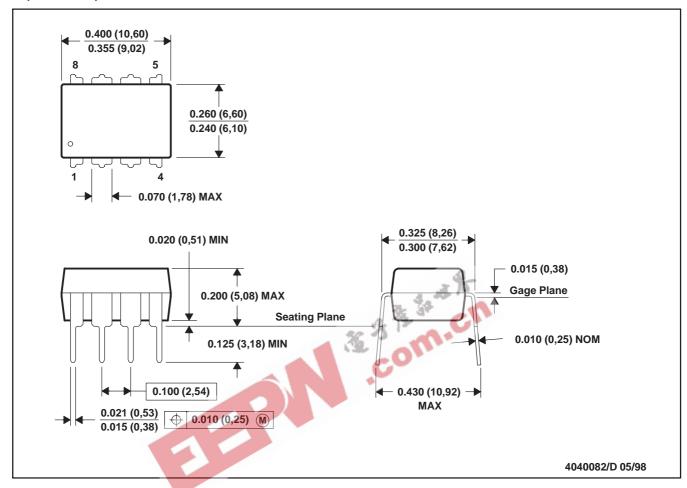


- NOTES: A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package can be hermetically sealed with a metal lid.
 - D. The terminals are gold plated.
 - E. Falls within JEDEC MS-004



P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

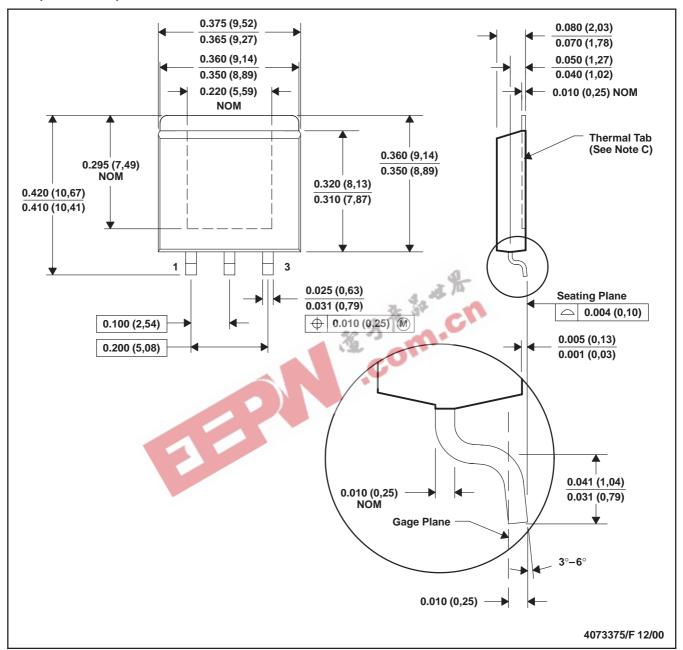
C. Falls within JEDEC MS-001

For the latest package information, go to http://www.ti.com/sc/docs/package/pkg_info.htm



KTE (R-PSFM-G3)

PowerFLEX™ PLASTIC FLANGE-MOUNT



NOTES: A. All linear dimensions are in inches (millimeters).

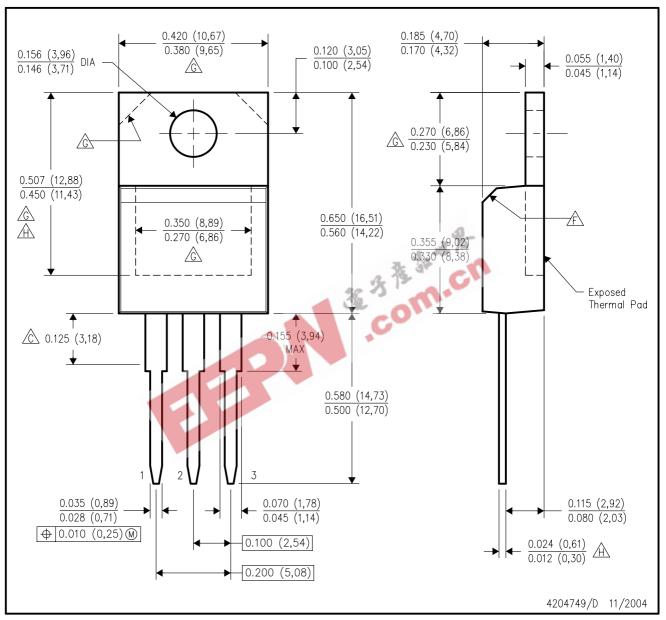
- B. This drawing is subject to change without notice.
- C. The center lead is in electrical contact with the thermal tab.
- D. Dimensions do not include mold protrusions, not to exceed 0.006 (0,15).
- E. Falls within JEDEC MO-169

PowerFLEX is a trademark of Texas Instruments.



KCS (R-PSFM-T3)

PLASTIC FLANGE-MOUNT PACKAGE



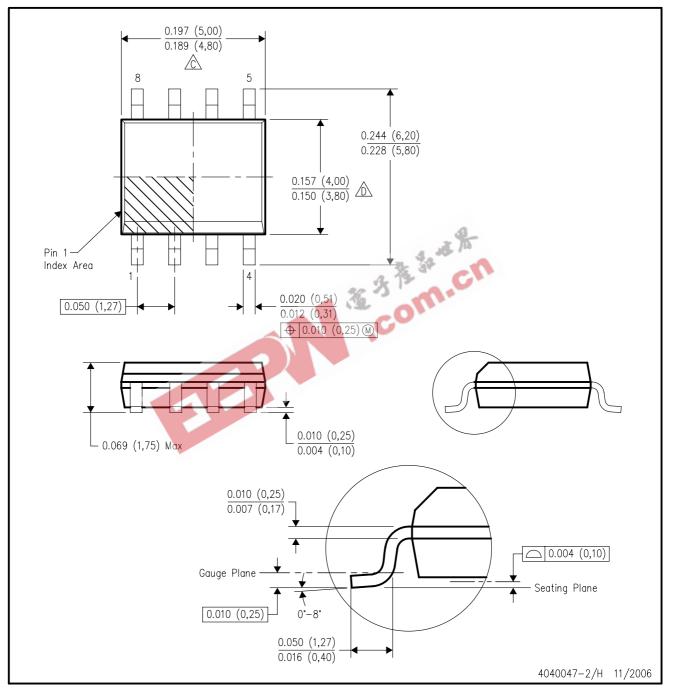
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Lead dimensions are not controlled within this area.
- D. All lead dimensions apply before solder dip.
- E. The center lead is in electrical contact with the mounting tab.
- The chamfer is optional.
- Thermal pad contour optional within these dimensions.
- ⚠ Falls within JEDEC T0—220 variation AB, except minimum lead thickness and minimum exposed pad length.



D (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



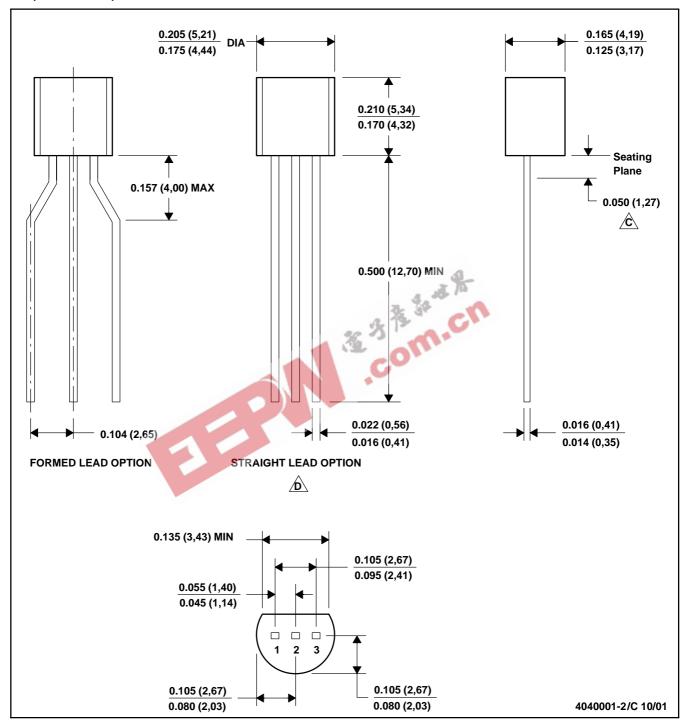
NOTES:

- A. All linear dimensions are in inches (millimeters). B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AA.



LP (O-PBCY-W3)

PLASTIC CYLINDRICAL PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

Lead dimensions are not controlled within this area

D. FAlls within JEDEC TO -226 Variation AA (TO-226 replaces TO-92)

E. Shipping Method:

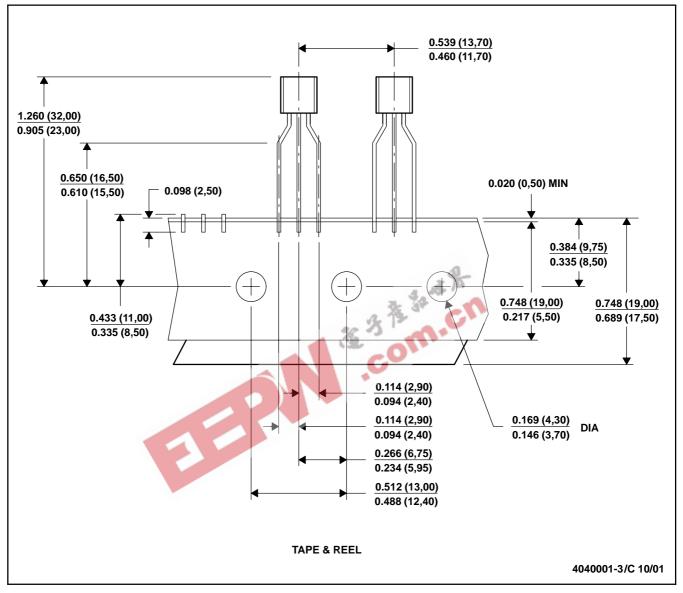
Straight lead option available in bulk pack only.
Formed lead option available in tape & reel or ammo pack.



1

LP (O-PBCY-W3)

PLASTIC CYLINDRICAL PACKAGE



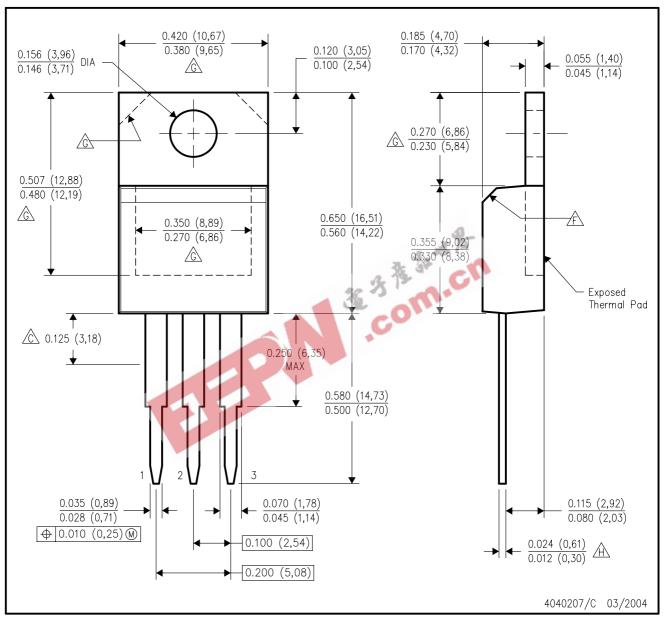
NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Tape and Reel information for the Format Lead Option package.

KC (R-PSFM-T3)

PLASTIC FLANGE-MOUNT PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Lead dimensions are not controlled within this area.
- D. All lead dimensions apply before solder dip.
- E. The center lead is in electrical contact with the mounting tab.
- The chamfer is optional.
- Thermal pad contour optional within these dimensions.
- ⚠ Falls within JEDEC TO—220 variation AB, except minimum lead thickness.



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Post Office Box 655303 Dallas, Texas 75265